



Product Summary

BV _{DSS}	Rds(on) Max	I _D Max T _A = +25°C
-20V	75mΩ @ V _{GS} = -4.5V	-3.8A
-200	137mΩ @ V _{GS} = -2.5V	-3.0A

Description

This MOSFET is designed to minimize on-state resistance (RDS(ON)) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Features

- Low On-Resistance
- Low Input Capacitance
- Low Profile, 0.6mm Max Height
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/guality/product-definitions/

Applications

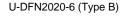
- Load Switch
- **Power Management Functions**
- Portable Power Adaptors

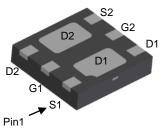
Mechanical Data

- Case: U-DFN2020-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @4
- Terminals Connections: See Diagram Below
- Weight: 0.0065 grams (Approximate)

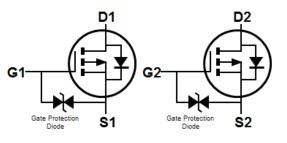


Notes:





Bottom View



Q1 P-CHANNEL MOSFET Q2 P-CHANNEL MOSFET Internal Schematic

Ordering Information (Note 4)

Part Number	Case	Packaging
DMP2075UFDB -7	U-DFN2020-6 (Type B)	3,000/Tape & Reel
DMP2075UFDB -13	U-DFN2020-6 (Type B)	10,000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

Site 1

U-DFN2020-6 (Type B)



O3 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key

Year	2017		2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	E		Н		J	К	L	М	Ν	0	Р	R
			1						-	-		
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Site 2



O3 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 0 = 2020) W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key

Year	2017	 2020	2021	2022	2023	2024	2025	2026	2027	2028	2029
Code	7	 0	1	2	3	4	5	6	7	8	9

Week	1-26	27-52	53
Code	A-Z	a-z	Z

Internal Code	Sun	Mon	Tue	Wed	Thu	Fri	Sat
Code	Т	U	V	W	Х	Y	Z



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage			Vdss	-20	V
Gate-Source Voltage			V _{GSS}	±8	V
Continuous Drain Current (Note 5) $V_{GS} = -4.5V$ State State State T _A = +25°C T _A = +70°C				-3.8 -3.0	А
Maximum Continuous Body Diode Forward Current (Note 5)	•	•	ls	-1.0	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	Ідм	-25	А		
Avalanche Current (Note 7) L = 0.1mH	las	-13	А		
Avalanche Energy (Note 7) L = 0.1mH	Eas	8.5	mJ		

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	PD	0.7	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	178	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	Po	1.4	W
Thermal Resistance, Junction to Ambient (Note 6) Steady State		Reja	92	°C/W
Thermal Resistance, Junction to Case (Note 6)	R _{0JC}	22	C/VV	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)	·					
Drain-Source Breakdown Voltage	BVDSS	-20	—	—	V	$V_{GS} = 0V, I_{D} = -250 \mu A$
Zero Gate Voltage Drain Current TJ = +25°C	IDSS	_	_	-1.0	μA	$V_{DS} = -20V, V_{GS} = 0V$
Gate-Source Leakage	lgss	_	_	±10	μA	$V_{GS} = \pm 6.4 V, V_{DS} = 0 V$
ON CHARACTERISTICS (Note 8)	·				•	•
Gate Threshold Voltage	Vgs(th)	-0.35	_	-1.4	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$
Static Drain-Source On-Resistance		_	53	75		VGS = -4.5V, ID = -2.9A
Static Drain-Source On-Resistance	RDS(ON)	_	64	137	mΩ	$V_{GS} = -2.5V, I_D = -2.3A$
Diode Forward Voltage	Vsd	_	-0.7	-1.2	V	V _{GS} = 0V, I _S = -3.0A
DYNAMIC CHARACTERISTICS (Note 9)	·				•	•
Input Capacitance	C _{iss}	_	642	—	pF	
Output Capacitance	Coss	_	98	_	pF	V _{DS} = -10V, V _{GS} = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	87	_	pF	
Gate Resistance	Rg	_	26.5		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = -4.5V)		_	8.8		nC	
Total Gate Charge (V _{GS} = -8V)	Qg	_	15		nC	
Gate-Source Charge	Qgs	_	0.9	_	nC	V _{DS} = -10V, I _D = -3.7A
Gate-Drain Charge	Q _{gd}		2.9		nC	7
Turn-On Delay Time	tD(ON)		5.5		ns	
Turn-On Rise Time	t _R		22.6		ns	V _{DD} = -10V, V _{GS} = -4.5V,
Turn-Off Delay Time	tD(OFF)	_	34.1	—	ns	$R_L = 3.3\Omega, R_g = 1\Omega$
Turn-Off Fall Time	tF	_	34.3	—	ns	
Body Diode Reverse Recovery Time	t _{RR}	—	13	—	ns	Is = -3.0A, dI/dt = 100A/µs
Body Diode Reverse Recovery Charge	Q _{RR}	_	3.3	_	nC	I _S = -3.0A, dI/dt = 100A/µs

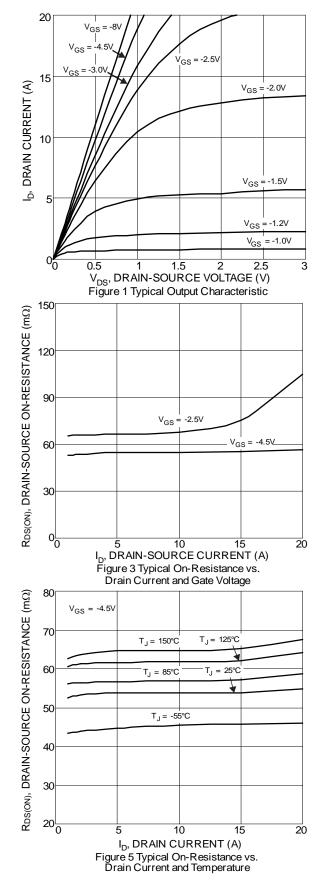
Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided
6. Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.
8. Short duration pulse test used to minimize self-heating effect.
9. Coverseted by device. Not service the restrict testing.

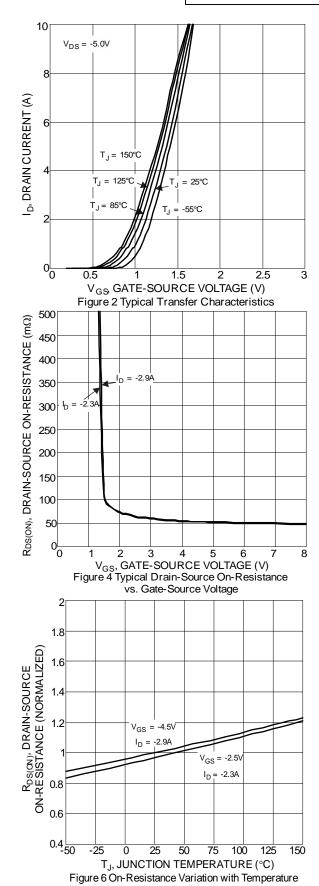
9. Guaranteed by design. Not subject to product testing.

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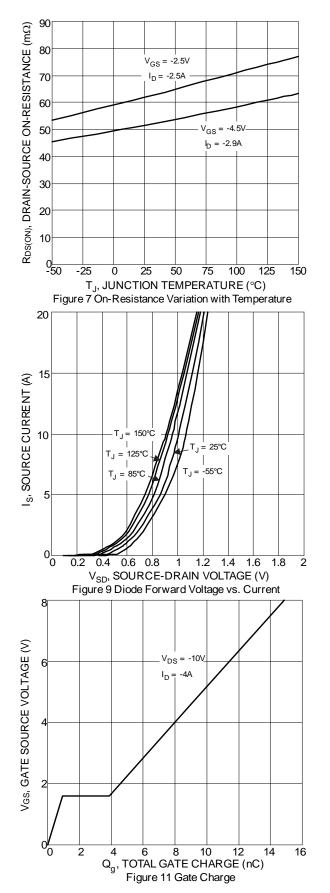


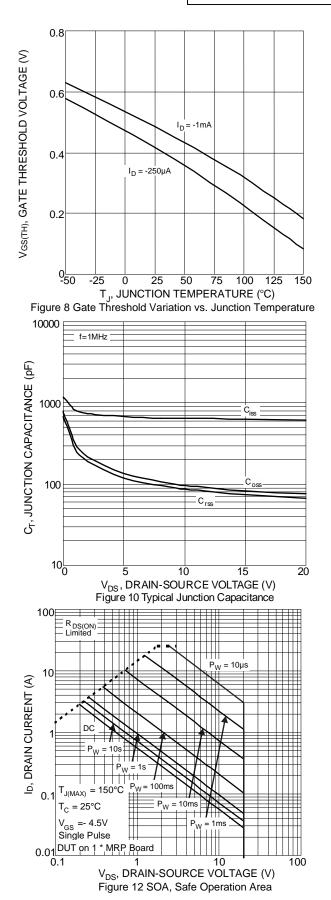
DMP2075UFDB



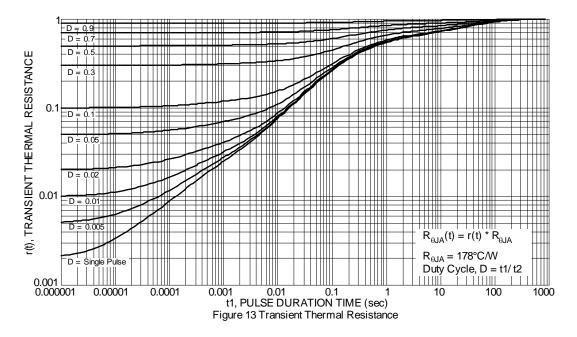








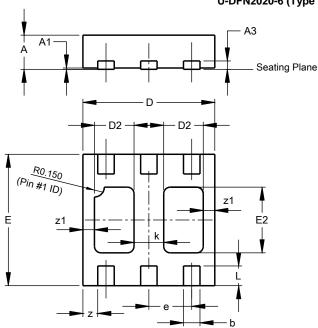






Package Outline Dimensions

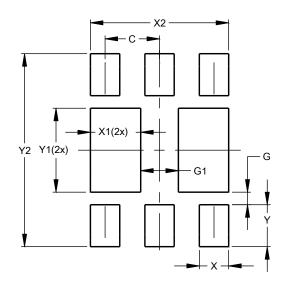
Please see http://www.diodes.com/package-outlines.html for the latest version.



	U-DFN2020-6 (Type B)							
Dim	Min	Max	Тур					
Α	0.545	0.605	0.575					
A1	0.00	0.05	0.02					
A3	-	-	0.13					
b	0.20	0.30	0.25					
D	1.95	2.075	2.00					
D2	0.50	0.70	0.60					
е	-	-	0.65					
E	1.95	2.075	2.00					
E2	0.90	1.10	1.00					
k	-	-	0.45					
L	0.25	0.35	0.30					
z	-	-	0.225					
z1	-	-	0.175					
All	Dimens	ions in	mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Value Dimensions (in mm) С 0.650 G 0.150 G1 0.450 Х 0.350 X1 0.600 X2 1.650 Y 0.500 Y1 1.000 2.300 Y2

U-DFN2020-6 (Type B)

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